

DFN1006-2L Plastic-Encapsulate ESD Protection Diodes

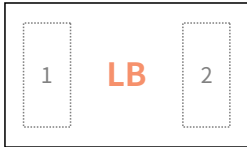
Features

- Low leakage current
- DFN1006-2L surface mount package
- IEC 61000-4-2 (ESD Air): ±20kV
- IEC 61000-4-2 (ESD Contact): ±20kV
- IEC 61000-4-5 (Lightning 8/20μs): 8A

Applications

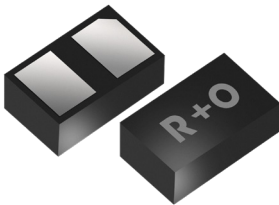
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation,Digital Cameras
- Peripherals, Audio Players, Industrial Equipment

Function Diagram



Reverse Working Voltage  
15V Max.  
Normal capacitance  
20pF(Typ.)

DFN1006-2L

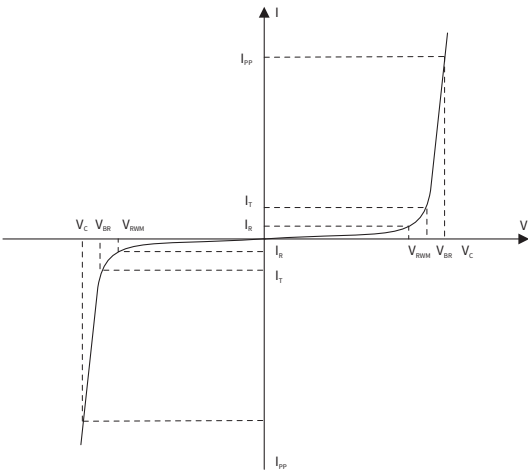


Maximum Ratings (Ta=25°C Unless otherwise specified)

| SYMBOL           | PARAMETER                           | CONDITIONS                      | VALUE       | UNIT |
|------------------|-------------------------------------|---------------------------------|-------------|------|
| V <sub>ESD</sub> | Electrostatic Discharge Voltage     | ESD per IEC 61000-4-2( Air )    | ±20         | KV   |
|                  |                                     | ESD per IEC 61000-4-2( Contact) | ±80         | KV   |
| P <sub>PP</sub>  | Peak Pulse Power                    | tp = 8/20 μs                    | 250         | W    |
| I <sub>PP</sub>  | Rated Peak Pulse Current            | tp = 8/20 μs                    | 8.0         | A    |
| T <sub>J</sub>   | Operating JunctionTemperature Range | —                               | -55 to +125 | °C   |
| T <sub>STG</sub> | Operating JunctionTemperature Range | —                               | -55 to +125 | °C   |

Electrical Parameter

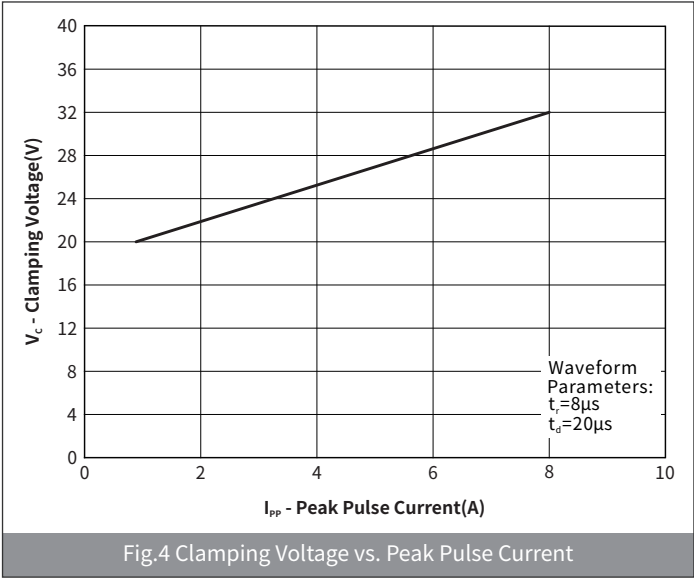
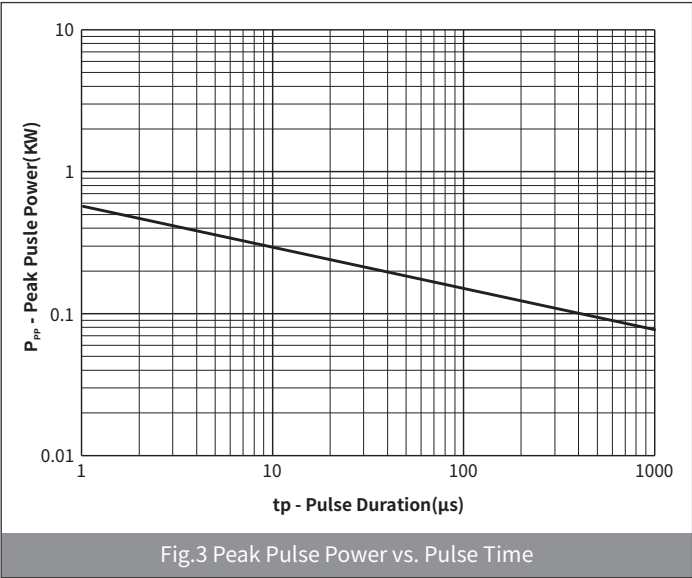
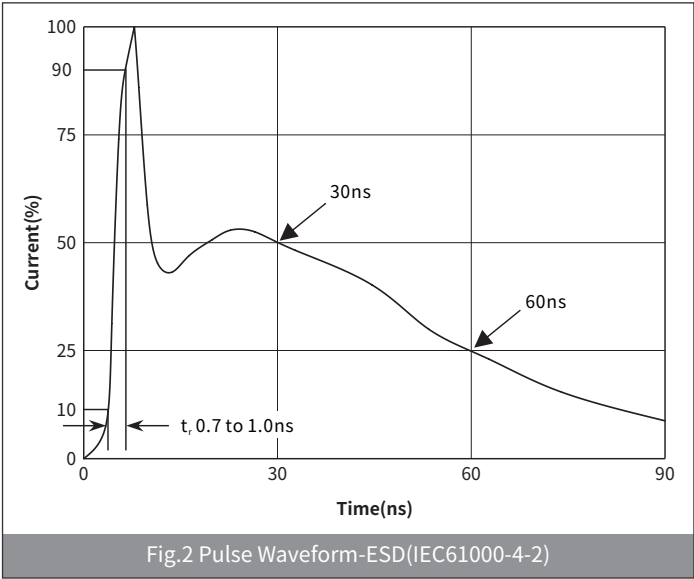
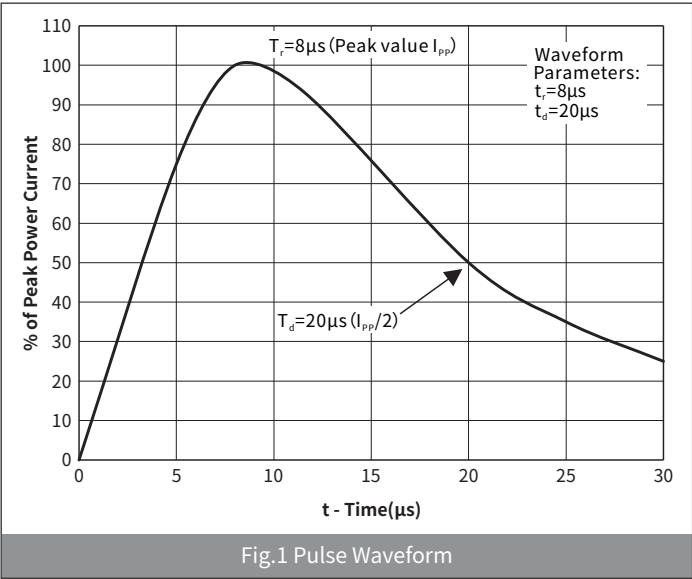
| SYMBOL           | PARAMETER                                        |
|------------------|--------------------------------------------------|
| V <sub>C</sub>   | Clamping Voltage @ I <sub>PP</sub>               |
| V <sub>BR</sub>  | Breakdown Voltage @ I <sub>T</sub>               |
| I <sub>PP</sub>  | Peak Pulse Current                               |
| I <sub>T</sub>   | Test Current                                     |
| I <sub>R</sub>   | Reverse Leakage Current @ VRWM                   |
| V <sub>RWM</sub> | Peak Reverse Working Voltage                     |
| P <sub>PP</sub>  | Peak Pulse Power Dissipation                     |
| C <sub>J</sub>   | Junction Capacitance @ V <sub>R</sub> =0V,f=1MHz |
| I <sub>F</sub>   | Forward Current                                  |
| V <sub>F</sub>   | Forward Voltage @I <sub>F</sub>                  |



● Electrical Characteristics (Ta=25°C Unless otherwise specified)

| PARAMETER                    | SYMBOL    | CONDITION                  | Min  | Typ | Max | UNIT    |
|------------------------------|-----------|----------------------------|------|-----|-----|---------|
| Peak Reverse Working Voltage | $V_{RWM}$ | $T_a=25^{\circ}C$          | —    | —   | 15  | V       |
| Breakdown Voltage            | $V_{BR}$  | $I_R=1mA, T_a=25^{\circ}C$ | 16.7 | —   | —   | V       |
| Reverse Leakage Current      | $I_R$     | $V_R=15V, T_a=25^{\circ}C$ | —    | 0.1 | 0.5 | $\mu A$ |
| Clamping Voltage             | $V_C$     | $I_{PP}=8A, t_p=8/20\mu s$ | —    | —   | 32  | V       |
| Junction Capacitance         | $C_J$     | $V_R=0V, f=1MHz$           | —    | 20  | 25  | pF      |

● Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



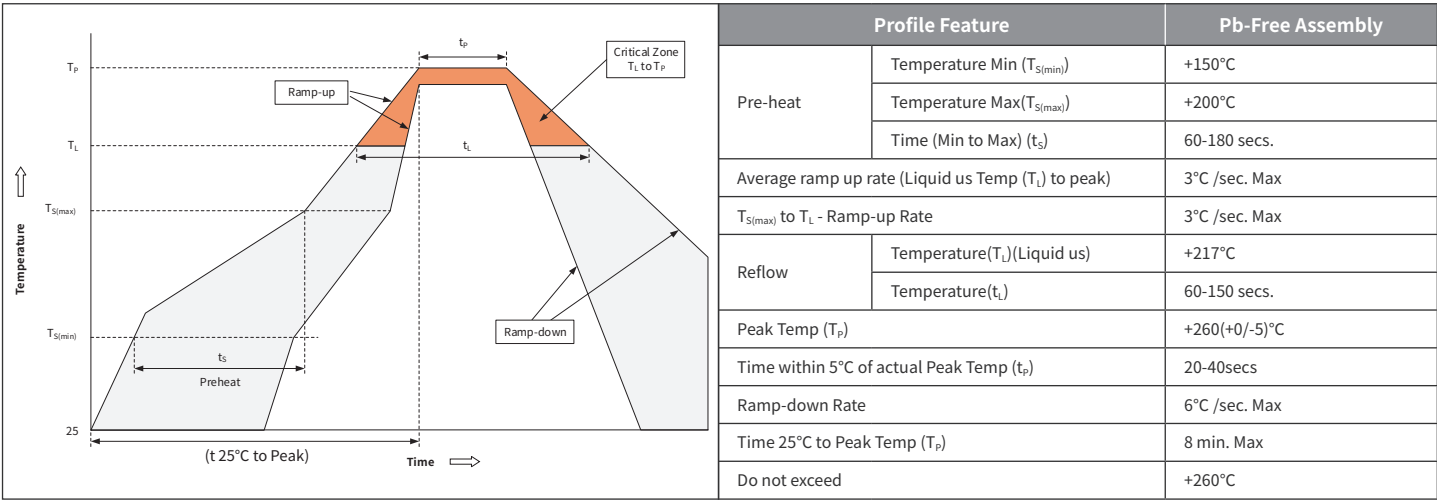
# H15VN10BA

Bi-directional 15V Normal Capacitance ESD

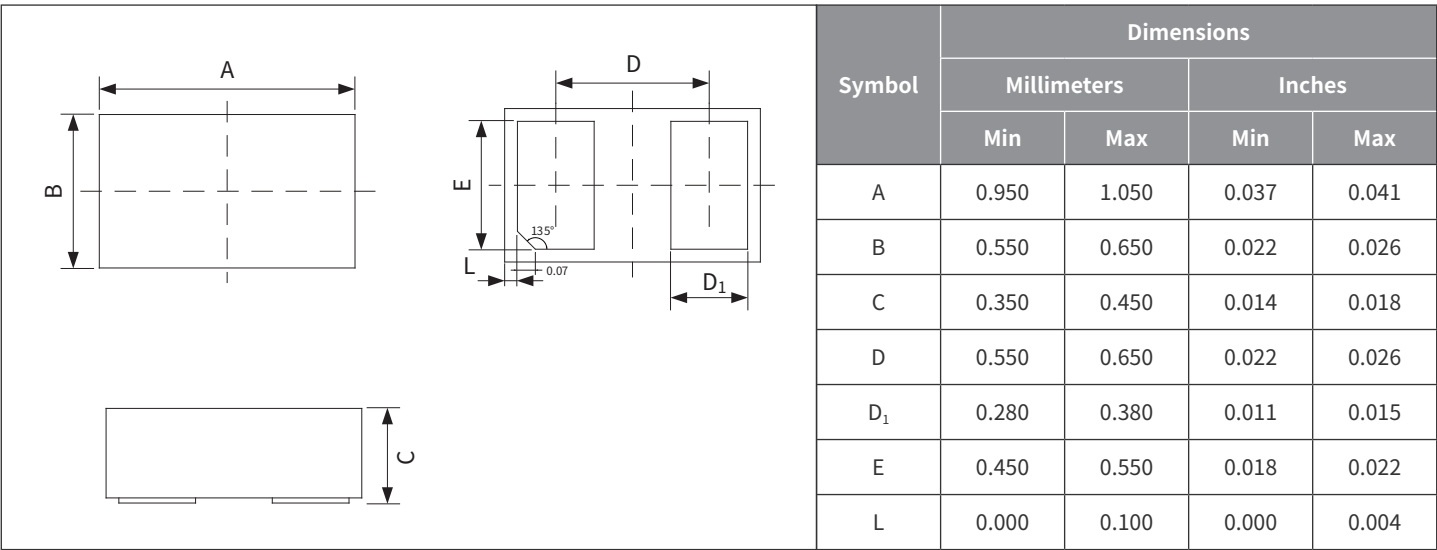
## Ordering Information

| PREFERED P/N | PACKAGE    | SIZE(mm)       | DELIVERY MODE | MPQ(PCS) |
|--------------|------------|----------------|---------------|----------|
| H15VN10BA    | DFN1006-2L | 1.00×0.60×0.37 | 7" REEL       | 10,000   |

## Recommended Soldering Conditions



## Package Outline Dimensions (DFN1006-2L)



## Suggested Pad Layout

